

Features

- 0.52" (13.20mm) Digit Height
- Four Digit Display
- Black/Grey Face, White Segment
- IC compatible, Easy assembly
- Dynamic drive connect
- RoHS Compliant, Pb Free

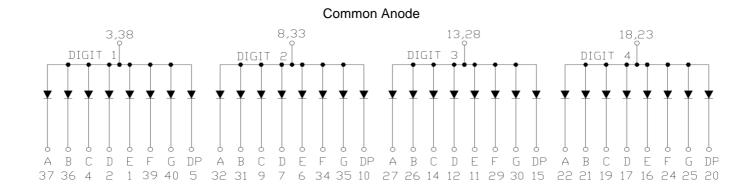
Applications

- Consumer Electronics
- Industrial Equipment

Description

The INND-TQ52 series is a 0.52" four digit display. It is a through hole type LED display which can be used in various applications.

Internal Circuit Diagram



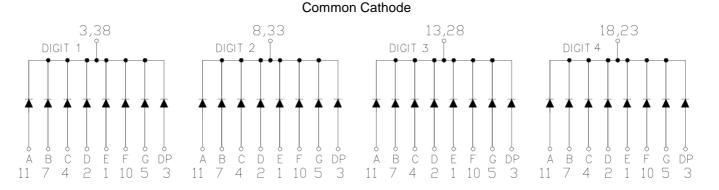


Figure 1. INND-TQ52 series Internal Circuit Diagram



Package Dimensions

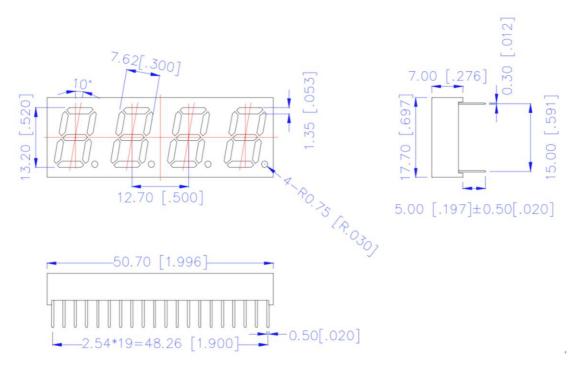


Figure 2. INND-TQ52 series Package Dimensions

Notes

- 1. All pins are Ø0.51[.020]±0.1[.004]
- 2. Dimension in millimeter [inch], tolerance is ± 0.25 [.010] and angle is $\pm 1^{\circ}$ unless otherwise noted.
- 3. Bending≤Length*1%.

All Light On Segments Feature & Pin Position

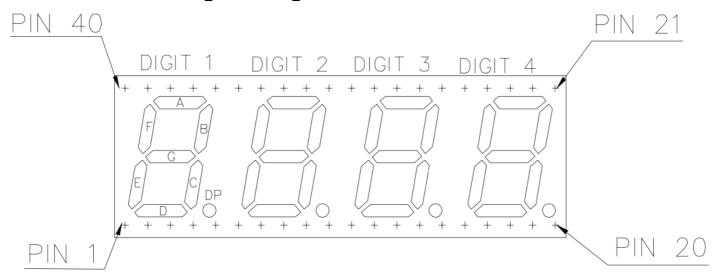


Figure 3. All Light On Segments Feature & Pin Position

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Absolute Maximum Rating at 25°C (Note 1)

Product (Per Segment)	Emission Color	Technology	P _d (mW)	I _F (mA)	I _{FP} * (mA)	V _R (V)	Derate From 25°C (mA/°C)	Top (°C)	T _{ST} (°C)
INND-TQ52YGXX	Yellow Green	AlGaInP	70	25	90	5	0.33	-35°C~+85°C	-35°C~+85°C
INND-TQ52YXX	Yellow	AlGaInP	70	25	90	5	0.33	-35°C~+85°C	-35°C~+85°C
INND-TQ52AXX	Amber	AlGaInP	70	25	90	5	0.33	-35°C~+85°C	-35°C~+85°C
INND-TQ52RXX	Red	AlGaInP	70	25	90	5	0.33	-35°C~+85°C	-35°C~+85°C
INND-TQ52DRXX	Deep Red	AlGaInP	70	25	90	5	0.33	-35°C~+85°C	-35°C~+85°C
INND-TQ52GXX	Green	InGaN	114	30	100	5	0.4	-35°C~+85°C	-35°C~+85°C
INND-TQ52BXX	Blue	InGaN	114	30	100	5	0.4	-35°C~+85°C	-35°C~+85°C
INND-TQ52WXX	White	InGaN	114	30	100	5	0.4	-35°C~+85°C	-35°C~+85°C

Notes

^{1.} Condition for IFP is pulse of 1/10 duty and 0.1msec width

INND-TQ52 Series 0.52" Through Hole Four Digit Display

Electrical Characteristics T_A = 25 °C (Note 1)

		VF	(V)@20	mA	λ(nm)@	210mA	I*V(n	ncd)@1	0mA	IR(μA)@VR=5V	IV-M @IF =10mA
Product (Per Segment)	Emission Color	min	typ.	max	λD	λР	min	typ.	max	max	max
INND-TQ52YGXX	Yellow Green	-	2.0	2.8	570	572	-	9	-	100	2:1
INND-TQ52YXX	Yellow	-	2.0	2.8	590	592	-	42	1	100	2:1
INND-TQ52AXX	Amber	ı	2.0	2.8	605	612	ı	59	ı	100	2:1
INND-TQ52RXX	Red	-	2.0	2.8	630	644	-	20	-	100	2:1
INND-TQ52DRXX	Deep Red		2.0	2.8	645	660	-	15	ı	100	2:1
INND-TQ52GXX	Green	-	3.2	3.8	525	-	-	219	-	100	2:1
INND-TQ52BXX	Blue	ı	3.2	3.8	465		-	20	ı	50	2:1
INND-TQ52WXX	White	-	3.2	3.8	X: 0.27 Y: 0.25	-	-	72	-	100	2:1

Notes

1. Performance guaranteed only under conditions listed in above tables.

ESD Precaution

ATTENTION: Electrostatic Discharge (ESD) protection



The symbol above denotes that ESD precaution is needed. ESD protection for GaP and AlGaAs based chips is necessary even though they are relatively safe in the presence of low static-electric discharge. Parts built with AllnGaP, GaN, or/and InGaN based chips are STATIC SENSITIVE devices. ESD precaution must be taken during design and assembly.

If manual work or processing is needed, please ensure the device is adequately protected from ESD during the process.

Please be advised that normal static precautions should be taken in the handling and assembly of this device to prevent damage or degradation which may be induced by electrostatic discharge (ESD).



Characteristic Curves for YG, Y, A, R, DR, G

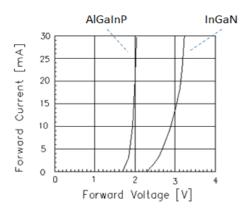


Fig 1. Forward Current vs. Forward Voltage

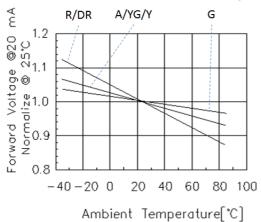


Fig 3. Forward Voltage vs. Temperature

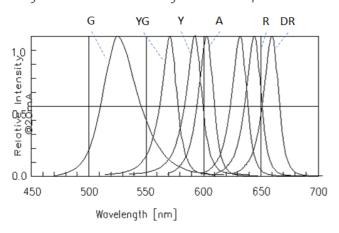


Fig 5. Relative Intensity vs. Wavelength

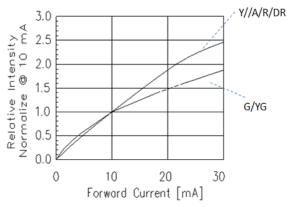


Fig 2. Relative Intensity vs. Forward Current

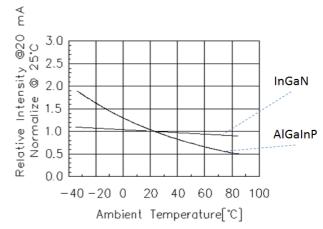


Fig 4. Relative Intensity vs. Temperature

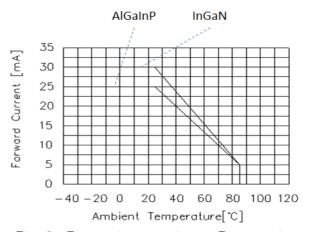


Fig 6. Forward current vs. Temperature



Characteristic Curves for B

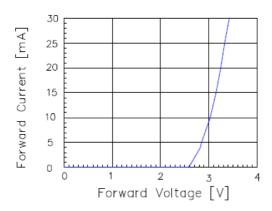


Fig 1. Forward Current vs. Forward Voltage

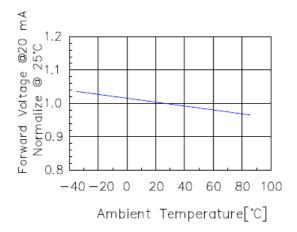


Fig 3. Forward Voltage vs. Temperature

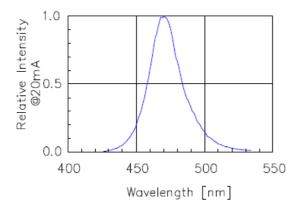


Fig 5. Relative Intensity vs. Wavelength

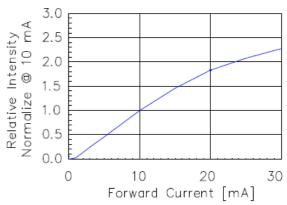


Fig 2. Relative Intensity vs. Forward Current

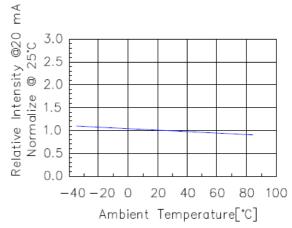


Fig 4. Relative Intensity vs. Temperature

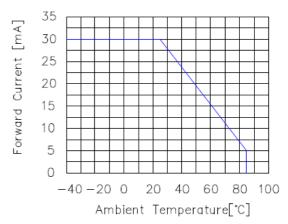


Fig 6, Forward current vs. Temperature



Characteristic Curves for W

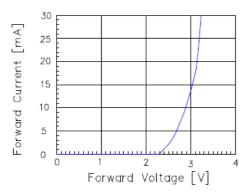


Fig 1. Forward Current vs. Forward Voltage

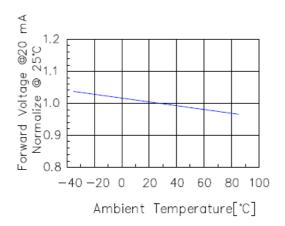


Fig 3. Forward Voltage vs. Temperature

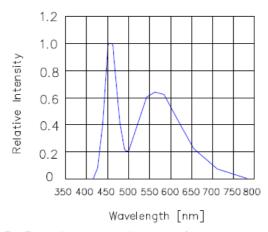


Fig 5, Relative Intensity vs. Wavelength

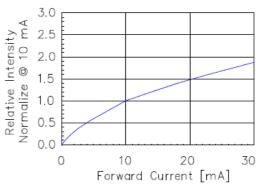


Fig 2, Relative Intensity vs. Forward Current

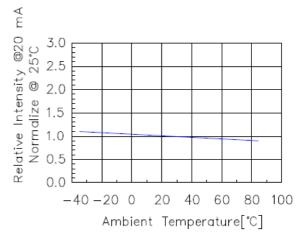


Fig 4. Relative Intensity vs. Temperature

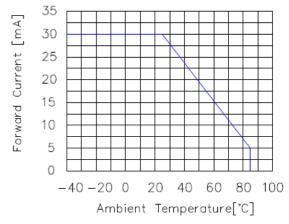
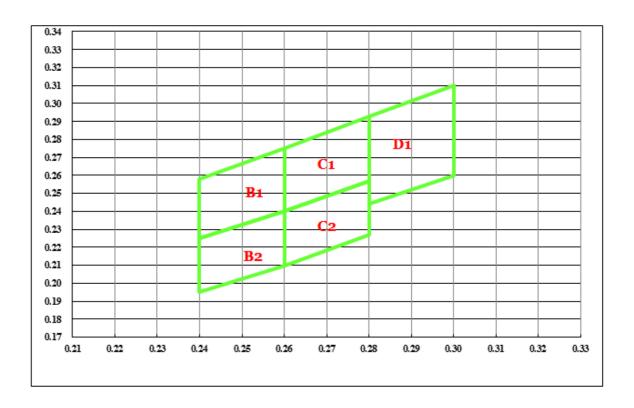


Fig 6. Forward current vs. Temperature



Chromaticity Bin (for White only)



		B1		
Х	0.240	0.240	0.260	0.260
Υ	0.225	0.258	0.275	0.240

		B2		
X	0.240	0.240	0.260	0.260
Υ	0.195	0.225	0.240	0.210

		C1		
Х	0.260	0.260	0.280	0.280
Υ	0.240	0.275	0.293	0.257

		C2		
X	0.260	0.260	0.280	0.280
Υ	0.210	0.240	0.257	0.227

		D1		
X	0.280	0.280	0.300	0.300
Y	0.244	0.293	0.310	0.260



Ordering Information

	T		ı	1	ı	1	
Product	Emission Color	Technology	I*V(mcd) @10mA	VF(V) @20mA	Polarity	Face Color	Orderable Part Number
					Common Anode	Black	INND-TQ52YGAB
INND TOFOVOVV	Valley Cross	AlColoD	0	2.0	Common Cathode	Black	INND-TQ52YGCB
INND-TQ52YGXX	Yellow Green	AlGaInP	9	2.0	Common Anode	Grey	INND-TQ52YGAG
					Common Cathode	Grey	INND-TQ52YGCG
					Common Anode	Black	INND-TQ52YAB
IND TOTOLOGY	Yellow	AlGalnP	43	2.0	Common Cathode	Black	INND-TQ52YCB
INND-TQ52YXX	Yellow				Common Anode	Grey	INND-TQ52YAG
					Common Cathode	Grey	INND-TQ52YCG
					Common Anode	Black	INND-TQ52AAB
ININD TOF2AVV	Amber				Common Cathode	Black	INND-TQ52ACB
INND-TQ52AXX	Amber	AlGaInP	59	2.0	Common Anode	Grey	INND-TQ52AAG
					Common Cathode	Grey	INND-TQ52ACG
					Common Anode	Black	INND-TQ52RAB
ININD TOESDAY	Dod	AIC claD	20	2.0	Common Cathode	Black	INND-TQ52RCB
INND-TQ52RXX	Red	AlGaInP	20	2.0	Common Anode	Grey	INND-TQ52RAG
					Common Cathode	Grey	INND-TQ52RCG

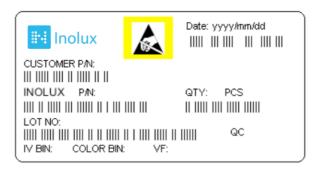


INND-TQ52 Series 0.52" Through Hole Four Digit Display

Product	Emission Color	Technology	I*V(mcd) @10mA	VF(V) @20mA	Polarity	Face Color	Orderable Part Number
					Common Anode	Black	INND-TQ52DRAB
INND-TQ52DRXX	Doop Bod	AlGalnP	15	2.0	Common Cathode	Black	INND-TQ52DRCB
IIVIND-1Q32DRAA	Deep Red	AlGaille	15	2.0	Common Anode	Grey	INND-TQ52DRAG
					Common Cathode	Grey	INND-TQ52DRCG
					Common Anode	Black	INND-TQ52GAB
INND TOF2CVV	Green	InGaN	219	3.2	Common Cathode	Black	INND-TQ52GCB
INND-TQ52GXX					Common Anode	Grey	INND-TQ52GAG
					Common Cathode	Grey	INND-TQ52GCG
					Common Anode	Black	INND-TQ52BAB
ININD TOTARYY	Dive			2.2	Common Cathode	Black	INND-TQ52BCB
INND-TQ52BXX	Blue	InGaN	20	3.2	Common Anode	Grey	INND-TQ52BAG
					Common Cathode	Grey	INND-TQ52BCG
					Common Anode	Black	INND-TQ52WAB
ININD TOFOWAY	\A/k !+-	In C - N	70	2.0	Common Cathode	Black	INND-TQ52WCB
INND-TQ52WXX	White	InGaN	72	3.2	Common Anode	Grey	INND-TQ52WAG
					Common Cathode	Grey	INND-TQ52WCG



Label Specifications



Inolux P/N:

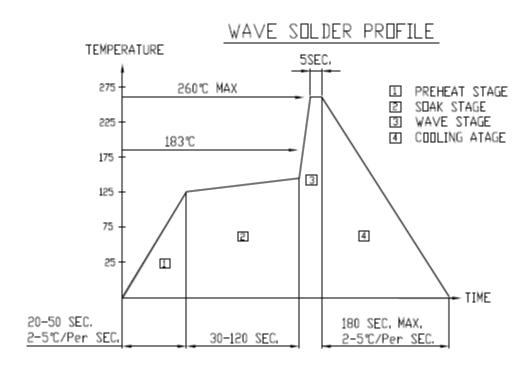
I	N	N	D	-	Т	Q	5	2	Х	Х	Х	-	Χ	Х	Х	Х
		-	olay pe		Display	у Туре	pe Dimension		Color	Polarity Face Colo			Customi Stamp-			
Ino	olux	Num	O = neric olay		T: Throu Q: Fou	_		0.52" Height	YG: 570 nm Y: 590 nm A: 605 nm R: 624 nm DR:645 nm G: 520 nm B: 470 nm W: X: 0.27 Y: 0.25	A = Common Anode C=Common Cathode	B = Black G = Grey					

Lot No.:

Z	2	0	1	7	01	24	001
Internal		Year (2017	Month	Data	Serial		
Tracker		Teal (2017	, 2010,)	IVIOTILIT	Date	Seriai	



Reflow Soldering



Soldering Iron

Basic Spec is \leq 4 sec. when 260°C (+10°C \Rightarrow -1 second). Power dissipation of Iron should be less than 15W. Surface temperature should be under 230°C

Rework

Rework should be completed within 4 second under 245°C



INND-TQ52 Series 0.52" Through Hole Four Digit Display

Revision History

Changes since last revision	Page	Version No.	Revision Date
Initial Release		1.0	12-27-2019

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- 2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.